December 17, 2012, Monday

| 08:00 am - 09:00 am | Breakfast PC Saxena Auditorium | |
|----------------------|---|--|
| PC Saxena Auditorium | | |
| 09:30 am – 10:15 am | Keynote- Prof. Kaushik Roy, Purdue University, USA Spin as State Variable for Computation: Prospects and Perspectives | |
| 10:15 am – 11:00 am | Keynote - Prof. Gerrit Bauer, TU Delft and Tohoku University, Japan Spin caloritronics –more than spin-dependent thermoelectric | |
| 11:00 am – 11:15 am | Tea break | |
| 11:15 am – 12.00 pm | Keynote- Prof. Nitin Samarth, Penn State University, USA Topological Insulators: New Routes To Semiconductor Spintronics | |
| 12:00 pm – 12:45 pm | Keynote – Prof. Juzer Vasi, EE, IIT Bombay Nanostructures for Photovoltaic Devices | |
| 12:45 pm – 02:00 pm | Lunch PC Saxena Auditorium | |

International Conference on Emerging Electronics ICEE 2012

December 15-17, 2012 **IIT Bombay**





Jointly organized by IIT Bombay and IISc Bangalore





Ministry of Science & Technology





ICEE Secretariat. Centre of Excellence in Nanoelectronics. Department of Electrical Engineering, Indian Institute of Technology Bombay, Powai, Mumbai - 400076, India.

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Session 2

Institute Auditorium, SOM

02:00 pm - 02:30 pm

Prof. B. Muralidharan, EE, IIT Bombay (Invited) *Power-efficiency trade-off in nanoscale thermoelectric* energy conversion

02:30 pm - 02:50 pm

Harshil N. Raval et al., IIT Bombay Solution Processed Organic Electronic Devices as Sensors for lonizing Radiation

02:50 pm – 03:20 pm

Rekha Singh et al., IIT Bombay Novel Layer by Layer (LBL) Approach for the Fabrication of Highly Transparent and Conducting Thin Films for Flexible Electronics, Based on PEDOT, via the Solution Processable Route

03:20 pm - 03:30 pm

Session 1

PC Saxena Auditorium

Dr. Sandeep Sangameswaran, Philips,

Electronic Packaging Challenges for Emerging Devices

Monika Bhattacharya et al., University of Delhi

Noise Temperature of InAlAs/InGaAs DG-HEMT

Naveen Karumuri et al., IIT Madras

Impact of Noise Temperature Constant and Diffusion

Coefficient on the Minimum Noise Figure and Minimum

An Analytical Charge Control Model for AlGaN/GaN HEMT

including the Gate bias dependence on Polarization Charge

Closing Ceremony

02:00 pm - 02:30 pm

Eindhoven (Invited)

02:30 pm - 02:50 pm

02:50 pm - 03:20 pm

PC Saxena Auditorium



Government of India **Department of Science & Technology**





December 15, 2012, Saturday

| 08:00 am - 09:00 am | Breakfast / Registration | PC Saxena Auditorium | | |
|--|---|---|--|--|
| PC Saxena Auditorium | 3 | r conchartationam | | |
| 09:30 am - 09:50 am | Inauguration and Welcor | ne address | | |
| 09:50 am - 10:35 am | - | Keynote - Prof. Ajay Sood, IISc Bangalore | | |
| | Nanotubes, Graphene and | Dendrimers based nanodevices | | |
| 10:35 am - 11:00 am | Tea break | | | |
| 11:00 am - 11:45 am | Keynote - Dr. Omkaram Nalamasu, CTO Applied Materials, USA Nanomanufacturing for electronics | | | |
| 11:45 am - 12:30 pm | Keynote- Prof. R. P. Jindal, Lousiana University, USA Harnessing a few to do the work of a million: The next technological challenge | | | |
| 12:30 pm - 02:00 pm | Lunch PC Saxena | Auditorium | | |
| Session 1 | | Session 2 | | |
| PC Saxena Auditorium | 1 | Institute Auditorium, SOM | | |
| 02:00 pm - 02:30 pm | | 02:00 pm - 02:30 pm | | |
| Dr. Ed Cartier, IBM (Invited) High K Metal Gates and Reliability | | Prof. Arindam Ghosh, IISc Bangalore (Invited) Achieving enhanced electro-optic functionality with hybrids of ultra-thin membranes | | |
| 02:30 pm - 03.00 pm | | 02:30 pm - 03.00 pm | | |
| Dr. Ben Kaczer, IMEC, Belgium (Invited) Assessing reliability of nano-scaled CMOS technologies one defect at a time | | Prof. H. Joerg Osten, Institute of Electronic Materials and Devices, Germany (Invited) Strain-driven enhancement of dielectric properties in thin metal oxides layers epitaxially grown on silicon | | |
| 03:00 pm - 04:00 pm Tea | Break and Poster Session | SOM Foyer | | |
| 04:00 pm - 04:20 pm Abhijit Mallick et al., University of Calcutta, Kolkata Spacer-Drain Overlap Dependence of Subthreshold Charac- teristics for Tunnel Field-Effect Transistors Based on Vertical Tunneling | | 04:00 pm - 04:20 pm Saibal Roy et al., Tyndall National Institute, Ire- Iand Self-aligned inkjet printing of organic TFTs/Circuits | | |
| 04:20 pm - 04:40 pm | | 04:20 pm - 04:40 pm | | |
| Revathy Padmanabhan et al., IISc Bangalore High-Density Metal-Insulator-Metal Capacitors Using Gd ₂ O ₃ -Based Dielectrics | | Sonali Das et al., BESU, Howrah Index tuned nanoparticle coating on dielectric film for improved photon transmission and enhanced performance for silicon solar cells | | |
| 04:45 pm- 06:15 pm PC Saxena Auditorium | Panel Discussion: Catalyzing and Sustaining Semiconductor Manufacturing in India Panel Members consist of representatives from Govt. of India (Deity, DRDO, etc.), Industry leaders (Applied Materials, IBM, etc.), Research consortia (IME, Albany Nanotech, etc.), and Academics. | | | |

07:30 pm - 10:00 pm Dinner PC Saxena Auditorium

December 16, 2012, Sunday

| 08:00 am - 09:00 am | Breakfast PC Saxe | na Auditorium | | |
|--|--------------------------|--|--|--|
| PC Saxena Auditoriur | n | | | |
| 09:30 am - 10:15 am | • | Keynote- Prof. Rao R. Tummala, Georgia Tech., USA Next Revolution in Electronics: System Scaling for Smart Mobile Systems | | |
| 10:15 am - 11:00 am | Director of Scientific R | Keynote- Dr. Marie-Noëlle Semeria, Director of Scientific Research, CEA Tech., France Low Power Nanoelectronics | | |
| 11:00 am - 11:15 am | Tea break | | | |
| 11:15 am - 12:00 pm | • | Keynote- Prof. Vikram Dalal, Iowa State University, USA Photovoltaic Energy Conversion: Status and Challenges | | |
| 12:00 pm - 12:45 pm | Green Energy Conversion | Keynote- Prof. Rajendra Singh, Clemson University, USA Green Energy Conversion & Storage for Solving India's Energy Problem through Innovation in Ultra Large Scale Manufacturing and Advanced Research of Solid State Devices and Systems | | |
| 12:45 pm - 02:00 pm | Lunch PC Saxe | na Auditorium | | |
| 02:00 pm - 02:45 pm | - | Keynote- Prof. Thomas Thundat, University of Alberta, Canada MEMS and NEMS for Standoff Sensing | | |
| 02:45 pm - 03:30 pm | | Keynote- Prof. Muhammad Ashraful Alam, Purdue University, USA In Search of a Landau Switch | | |
| 03:30 pm - 04:30 pm | Tea Break and Poster Se | ssion SOM Foyer | | |
| Session 1 | | Session 2 | | |
| PC Saxena Auditoriur | n | Institute Auditorium, SOM | | |
| 04:30 pm – 05:00 pm | | 04:30 pm – 05:00 pm | | |
| Prof. S. K. Ray, IIT Kharagpur (Invited) Nanocrystal Based Memory Devices | | Prof. Ananthasuresh, IISc, Bangalore (Invited) Micromechanical Signal Processors | | |
| 05:00 pm – 05:30 pm | | 05:00 pm – 05:30 pm | | |
| Prof. Saurabh Lodha, EE, IIT Bombay (Invited) Gate stack and source/drain engineering for enabling Ge CMOS | | Dr. M. K. Radhakrishnan, NanoRel. (Invited) Physical Analysis Challenges and Interface Physics Studie in Silicon Nanodevices | | |
| 05:30 pm – 05:50 pm | | 05:30 pm – 05:50 pm | | |
| Sandeep Lashkare et al., IIT Bombay Design of Epitaxial Si punch-through diode based selector for High Density Bipolar RRAM | | Harikrishnan V. et al., IIT Bombay Humidity Sensing Properties of Graphene Quantum Dots | | |
| 05:50 pm – 06:10 pm | | 05:50 pm – 06:10 pm | | |
| Naga Bharath Daka et al., IIT Madras Comparison of Direct Tunneling in Metal-GaN Schottky Junctions Using Different k • p Models for the Complex Bandstructure | | Mahidhar Nyayapati et al., IISc Bangalore Analog Vibration Spectrum Sensor | | |
| 06:10 pm – 06:30 pm | | 06:10 pm – 06:30 pm | | |
| Murali Golve et al., IIT Bombay Novel Architectures for Zinc-Oxide Junctionless Transistor | | Ajay Kushwaha et al., IIT Bombay Roughness Enhanced Surface Defects and Photoconduc- | | |